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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR 2SK3992

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3992 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

ORDERING INFORMATION

PART NUMBER	PACKAGE		
2SK3992	TO-251 (MP-3)		
2SK3992-ZK	TO-252 (MP-3ZK)		

FEATURES

Low on-state resistance
 R_{DS(on)1} = 4.8 mΩ MAX. (V_{GS} = 10 V, I_D = 32 A)

- Low Ciss: Ciss = 2900 pF TYP.
- 5 V drive available

(TO-251)



(TO-252)



ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (VGS = 0 V)	VDSS	25	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±64	Α
Drain Current (pulse) Note1	ID(pulse)	±256	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	38	W
Total Power Dissipation	P _{T2}	1.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	33	Α
Single Avalanche Energy Note2	Eas	109	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 12.5 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

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ELECTRICAL CHARACTERISTICS (TA = 25°C)

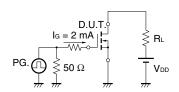
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 25 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	2.0	2.5	3.0	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 10 V, I _D = 16 A	12			S
Drain to Source On-state Resistance Note	R _{DS(on)1}	V _{GS} = 10 V, I _D = 32 A		3.4	4.8	mΩ
	R _{DS(on)2}	V _{GS} = 5.0 V, I _D = 16 A		5.9	10.8	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		2900		pF
Output Capacitance	Coss	V _{GS} = 0 V		640		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		440		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 12.5 V, I _D = 32 A		21		ns
Rise Time	tr	V _{GS} = 10 V		26		ns
Turn-off Delay Time	td(off)	$R_G = 10 \Omega$		69		ns
Fall Time	t f			32		ns
Total Gate Charge	Q _G	V _{DD} = 20 V		56		nC
Gate to Source Charge	Qgs	V _{GS} = 10 V		11		nC
Gate to Drain Charge	Q _{GD}	I _D = 64 A		19		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 64 A, V _{GS} = 0 V		0.94		V
Reverse Recovery Time	trr	I _F = 64 A, V _{GS} = 0 V		38		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		44		nC

Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

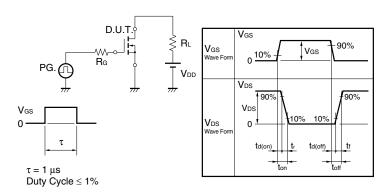
$V_{GS} = 20 \rightarrow 0 \text{ V}$ V_{DD} V_{DD} V_{DD} D.U.T. V_{DD} V_{DD} V_{DD} V_{DD} V_{DD} V_{DD} V_{DD}

TEST CIRCUIT 3 GATE CHARGE



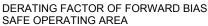
-Starting Tch

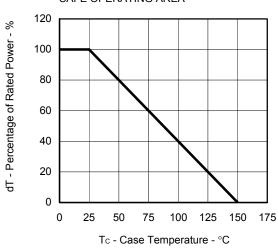
TEST CIRCUIT 2 SWITCHING TIME



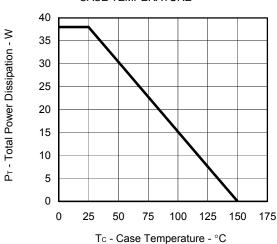


TYPICAL CHARACTERISTICS (TA = 25°C)

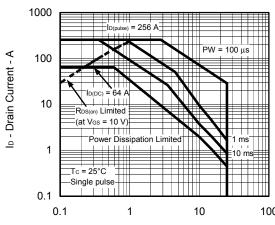


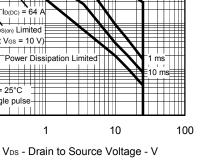


TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

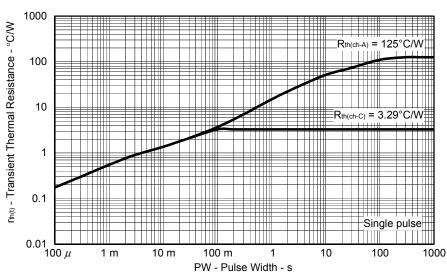


FORWARD BIAS SAFE OPERATING AREA



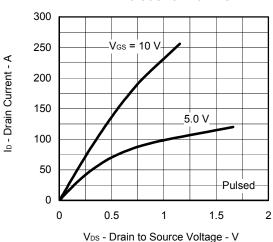


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

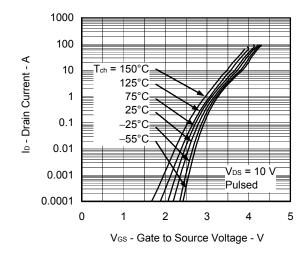


3

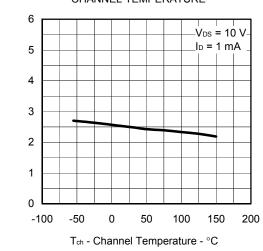
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



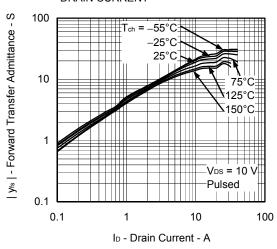
FORWARD TRANSFER CHARACTERISTICS



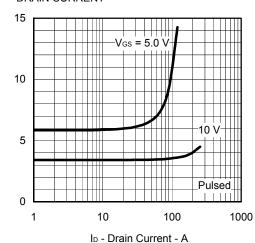
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



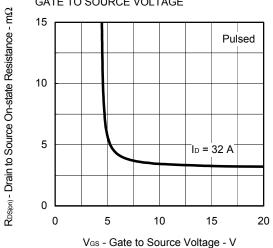
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. **DRAIN CURRENT**



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

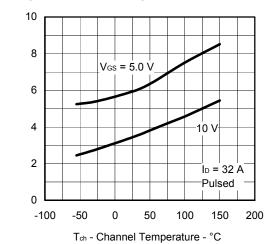


RDS(on) - Drain to Source On-state Resistance - m\Omega

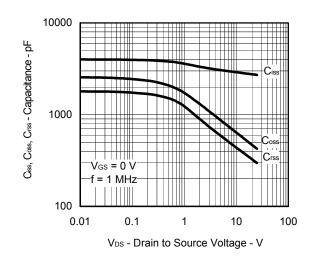
VGS(off) - Gate Cut-off Voltage - V

RDS(on) - Drain to Source On-state Resistance - m\Omega

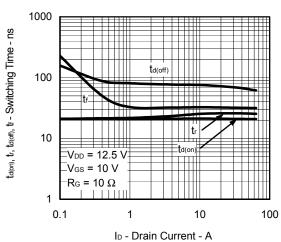
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



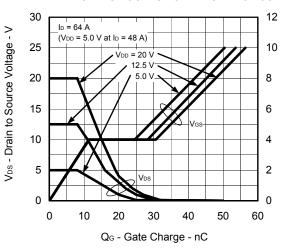
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



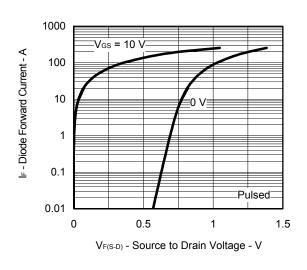
SWITCHING CHARACTERISTICS



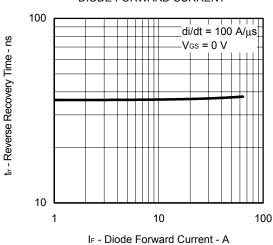
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE

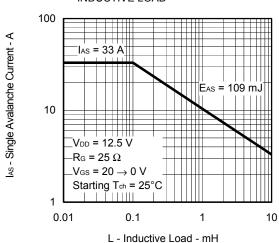


REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

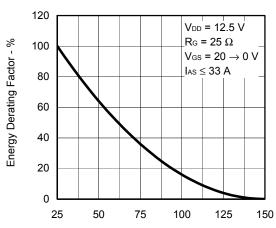


Ves - Gate to Source Voltage - V

SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



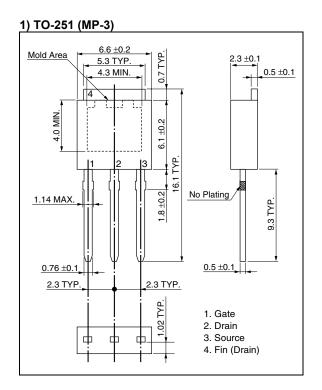
SINGLE AVALANCHE ENERGY DERATING FACTOR

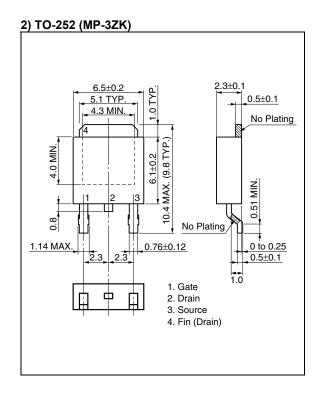


Starting Tch - Starting Channel Temperature - °C

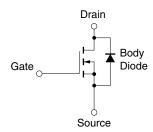


PACKAGE DRAWINGS (Unit: mm)





EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

Data Sheet D17321EJ1V0DS 7

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